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# Lightweight and Low-Loss 3-D Printed Millimeter-Wave Bandpass Filter Based on Gap-Waveguide

**BAHAA AL-JUBOORI**<sup>1,2</sup>, **JIAFENG ZHOU**<sup>1</sup>, **YI HUANG**<sup>1</sup>, (Senior Member, IEEE),  
**MUAAD HUSSEIN**<sup>1</sup>, **AHMED ALIELDIN**<sup>1</sup>, (Member, IEEE),  
**WILLIAM J. OTTER**<sup>3</sup>, (Member, IEEE),  
**DIRK KLUGMANN**<sup>4</sup>, (Member, IEEE), AND  
**STEPAN LUCYSZYN**<sup>3</sup>, (Fellow, IEEE)

<sup>1</sup>Department of Electrical Engineering and Electronics, University of Liverpool, Liverpool L69 3GJ, U.K.

<sup>2</sup>Department of Electronic and Communications Engineering, Al-Nahrain University, Baghdad 10070, Iraq

<sup>3</sup>Department of Electrical and Electronic Engineering, Imperial College London, London SW7 2AZ, U.K.

<sup>4</sup>S&AO Ltd and UKRI/STFC Rutherford Appleton Laboratory, Harwell Campus, Didcot OX11 0QX, U.K.

Corresponding author: Jiafeng Zhou (jiafeng.zhou@liverpool.ac.uk)

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**ABSTRACT** This paper presents a comprehensive study of a groove gap waveguide (also known as a waffle-iron) bandpass filter at Ka-band (26.5-40 GHz), fabricated using a high resolution polymer jetting (Polyjet) 3-D printing technology. The same filter was previously fabricated using brass CNC milling technology. The metalized Polyjet 3-D printed filter has lower loss, is lighter in weight and more cost-effective, when compared to the solid metal case. The filter operates at a center frequency of 35.65 GHz, has a 500 MHz bandwidth (1.4% fractional bandwidth), and has a transmission zero below and above the passband. Without any design iterations, the measured S-parameters for the Polyjet 3-D printed filter are presented and compared with simulated results, showing excellent agreement. A comparison is then made between the measured results and that of its brass machined counterpart. The new Polyjet 3-D printed filter is 85% lighter than the conventional machined version. All these features prove the important potential of 3-D printing technology for millimeter-wave applications, which includes aerospace.

**INDEX TERMS** Printing, bandpass filter, millimeter-wave band, gap waveguide, waffle-iron, Polyjet.

## I. INTRODUCTION

Low loss, low mass and easy of manufacture for bandpass filters (BPFs) operating at millimeter-wave (mm-wave) frequencies are of high importance for aerospace (unmanned drone, manned aircraft, satellite and interplanetary mission) applications. A large number of mm-wave BPFs using various design and fabrication technologies have been reported over the past few decades. For high frequency microwave/mm-wave applications, designers prefer metal-pipe rectangular waveguide solutions, due to their low loss and high power handling capabilities. Typical examples of waveguide BPF implementations have been demonstrated at X-band (8.2-12.4 GHz) [1] and Ku-band (12.4-18 GHz) [2]. One of the drawbacks with conventional waveguide components is the poor electrical contact between joined waveguide

parts, especially at mm-wave frequencies. To mitigate this, a very accurate machining process is required, which results in higher costs. In contrast, planar solutions are compatible with monolithic microwave integrated circuit (MMIC) applications, although the associated ohmic losses are relatively high, especially at mm-wave frequencies [3], [4]. Substrate integrated waveguide (SIW) technology has also been used to implement BPFs at mm-wave frequencies [5] Although SIWs present good integration capabilities, when compared to conventional waveguides, they can still suffer from high dielectric losses.

Air-filled SIW [6] and empty SIW (ESIW) [7], [8] have been proposed for manufacturing “empty” waveguides without having a dielectric substrate, but at the same time completely integrated into a planar substrate. This method is

compromised between the advantages of classical waveguide technologies, such as high quality (Q-)factor and low losses, and the advantages of planar circuits, such as low cost and easy compact integration. However, the Q-factor is still much lower than the conventional rectangular waveguides. This is because the conventional waveguides are much higher, which means more volume and more energy can be stored than in ESIWs (having the same height of the dielectric substrate in an SIW). To overcome this restriction, a novel integrated structure was proposed [9] to embed very high Q-factor filters based on the ESIW with an increased height. Nonetheless, due to the use of microstrip feed lines and transitions (from microstrip to ESIW), losses will increase.

Gap waveguide was proposed as an alternative to conventional metal-pipe rectangular waveguides, at extremely high frequencies (EHF) and beyond [10], as it avoids the use of (relatively lossy – e.g. typically  $6 \text{ dB m}^{-1}$  at W-band) sidewalls. Because of the small dimensions of the structures at mm-wave frequencies, fabrication of conventional waveguide components using longitude-cut fabrication techniques is challenging, due to radiation leakage from the physical connection mismatches of the waveguide pieces. Moreover, poor metal contact also leads to other undesirable effects, such as passive intermodulation (PIM). Gap waveguides consist of two parallel plates, being open from the sides. One of the plates is flat, which ideally acts as a perfect electrical conducting plane, while the other has a periodic structure of metal pins that are created to act as an artificial magnetic conductor [10], [11]. By choosing specific pin dimensions, a cut-off frequency for parallel-plate modes can be established; prohibiting wave propagation. To provide a path for electromagnetic propagation, a groove gap waveguide (GGW) or ridge gap waveguide is formed among the pins, where the waves transfer over the resonators through the groove or ridge, respectively [10], [12]. Similar to conventional rectangular waveguides, gap waveguides are usually manufactured using machining technology (e.g., by milling or drilling metal structures).

Low-cost gap waveguides have been proposed [13]–[16]. In the former two, half-height pins are employed in gap waveguide technology, making fabrication processing of the pin surface easier. However, an accurate manufacturing process is still needed. In the latter two, a novel cost-effective method to manufacture integrated waveguide structures at high frequencies has been presented. In this method, instead of pins, a truncated glide-symmetric holey EBG structure is adopted.

Gap waveguides are regarded as a compromise solution for mm-wave BPFs. Unlike planar and SIW technologies, gap waveguide filters are characterized by their high Q-factor and, thus, low losses at mm-wave frequencies. Also, the relatively lossy sidewalls between the top and bottom plates (found with conventional waveguides) are no longer needed, where periodic pins can be created on the borders of one of the parallel plates (in order to function as a high impedance surface). Over the last few years, many BPFs have been reported based

on gap waveguide (also known as waffle-iron) technology at X-band [17], [18], Ku-band [12], Ka-band (26.5–40 GHz) [19]–[21], Q-band (33–50 GHz) [22] and V-band (50–75 GHz) [23].

In this work, a low loss, lightweight and easy to manufacture GGW BPF is fabricated using high resolution Polyjet 3-D printing. The rest of the paper is organized as follows: Section II introduces a study of the main manufacturing techniques used to fabricate mm-wave filters. The design procedure of a BPF is shown in Section III. Simulation, fabrication and measurements for the proposed prototype are described in Section IV, with a conclusion in Section V.

## II. MILLIMETER-WAVE FILTER FABRICATION

Manufacturing microwave components to higher levels of accuracy, than those found at longer wavelengths, becomes increasingly more difficult as frequency increases. Different technologies can be adopted for the manufacture of BPFs operating at mm-wave frequencies. The choice of a manufacturing technology, to some extent, depends on the technology on which the filter is designed. For example, with conventional filter designs based on planar technology, printed circuit board (PCB) [24] or micromachining technology is adopted for manufacturing; while machining technology is used to fabricate waveguide or gap waveguide based filters. The merits and challenges of the four main manufacturing technologies that can be utilized to fabricate mm-wave BPFs will be briefly discussed.

### A. CO-FIRED CERAMIC

For harsh environments, including high humidity and high-temperatures, co-fired ceramic technology can be a good choice for component fabrication. Low temperature co-fired ceramic (LTCC) technology, with sintering below  $1,000^\circ\text{C}$ , is used to produce compact multilayer circuits. LTCC has been used to implement different mm-wave BPFs; for example, planar-based filter of 60 GHz [25], [26] and SIW-based filter at 40 GHz [5], 140 GHz [27], [28] and 174 GHz [29]. LTCC technology has many advantages for the manufacture of microwave BPFs. For example, ceramic materials provide highly robust performance under stringent environmental and mechanical conditions. Furthermore, unlike micromachining, 3-D structures having complex designs can be realized with a cost-effective fabrication technique, especially for medium and high volumes of manufacture. Having said this, LTCC-based mm-wave BPFs suffer from notably high insertion loss, when compared to some other fabrication technologies, such as machining and 3-D printing. Therefore, it is not desirable for the fabrication of high Q-factor and low-loss components.

### B. MICROMACHINING

Both bulk or surface micromachining technologies can be used to implement BPFs at (sub-)mm-wave frequencies [30]. Two waveguide filters, one operating in the WR-3 band (220–325 GHz) and the other in the WR-1.5 band

(500-750 GHz), were fabricated using SU-8. A comparative manufacturing study of sub-THz bandpass frequency selective surface (FSS) filters has been reported [31]. Photolithography facilitates batch processing, when compared to the other methods. However, the need for cleanroom microfabrication processing increases complexity, time to manufacture and ultimately cost.

### C. MACHINING

Machining technology is mainly used for metal-based component fabrication. For high Q-factor and low-loss BPFs, air-filled metal-pipe rectangular waveguide or gap waveguide technologies can be adopted. In recent years, many waveguide- and gap waveguide-based mm-wave BPFs have been fabricated using machining technology, by milling out or drilling into metal structures [2], [19]–[21], [32] and [33]. Machining technology is preferred for high-Q and low-loss components within the mm-wave band. However, the small dimensions of their structures (e.g., pin arrays in gap waveguide) increase the complexity of the milling or drilling process in machining technology and, hence, also the time and cost of fabrication. Additionally, with aerospace and satellite applications, excess mass is also an important factor.

### D. 3-D PRINTING

3-D printing technology is emerging for the fabrication of lightweight and low-loss components, as well as complex structured components operating at mm-wave frequencies [34]–[37]. 3-D printing technology can be mainly classified as either metal-based or polymer-based (with additional metal plating) 3-D printing. With the former, binder jetting/sintering and selective laser melting (SLM) can be adopted to construct metal-pipe rectangular waveguides, with Cu-15Sn powder melted layer by layer [38]. With the latter, metal-pipe rectangular waveguides have been demonstrated using fused deposition modelling (FDM) [36], stereolithographic apparatus (SLA) [36] and polymer-jetting (Polyjet) [39]. A variety of GGW-based prototypes operating at the Ka-band and manufactured by metallized 3-D printing technique have been presented [40]. Their work proved the potential of using 3-D printing technology to fabricate GGW structures at high frequencies. Furthermore, 3-D printing and metallization technology is adopted to fabricate a novel leaky-wave antenna based on gap waveguide technology [41]. In the work reported here, Polyjet 3-D printing of a groove gap waveguide BPF is demonstrated.

## III. FILTER DESIGN

### A. FILTER SPECIFICATIONS AND SYNTHESIS

To verify the proposed 3-D printing techniques, a mm-wave BPF is designed and fabricated, having the high selectivity design specifications given in TABLE 1. In this work, a high selectivity response is achieved with a lower number of resonators by introducing cross-coupling between one pair of non-adjacent resonators, to produce two transmission

TABLE 1. Target band-pass filter design specifications.

Parameter	Value
Filter Type	Quasi-elliptic
Center Frequency (GHz)	35.65
Fractional Bandwidth (FBW) (%)	1.4
Insertion Loss (dB)	< 0.5
Return Loss (dB)	> 15

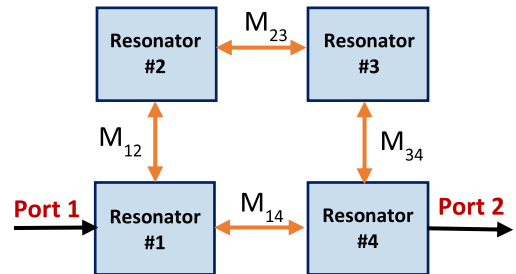


FIGURE 1. Topology of the filter.

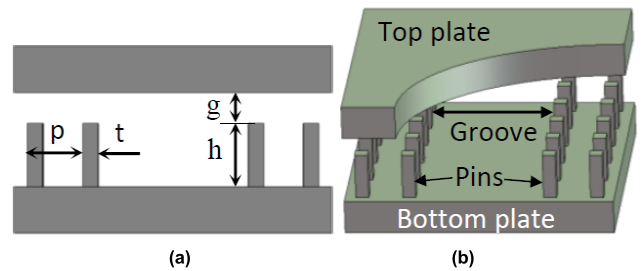


FIGURE 2. Gap waveguide periodic structure: (a) Cross-section; (b) 3D perspective view. (Dimensions listed in TABLE 2).

zeros around the passband. The resulting topology of this compact BPF is shown in FIGURE 1. The coupling coefficient ( $M$ ) between resonators and external quality factor ( $Q_e$ ) can be determined from the circuit elements of the low-pass prototype filter [42]. With reference to FIGURE 1,  $M_{ij}$  is the coupling coefficient between two resonators, where  $i$  and  $j$  identify different resonator numbers. These values are:  $M_{12} = M_{34} = 0.0168$ ,  $M_{23} = 0.0154$ ,  $M_{14} = -0.0043$  and  $Q_e = 48.878$ .

### B. DESIGN CURVES

On the (bottom) plate containing the periodic array of pins, the tips of these pins are separated from the (top) flat plate with a gap ( $g$ ). Based on the dispersion diagram [43], the dimensions of the unit cell are chosen to cover Ka-band, as shown in FIGURE 2. In gap waveguide, the height of the pins  $h \sim \lambda_o/4$  and the air gap separation distance  $g < \lambda_o/4$ , where  $\lambda_o$  is the wavelength in free space. To create a groove gap waveguide, some of the pins are removed to form four air-filled cavity resonators (named grooves), as illustrated in FIGURE 2. To obtain a resonance at 35.65 GHz, initially, the geometric shape of the cavities was chosen to be cubic.

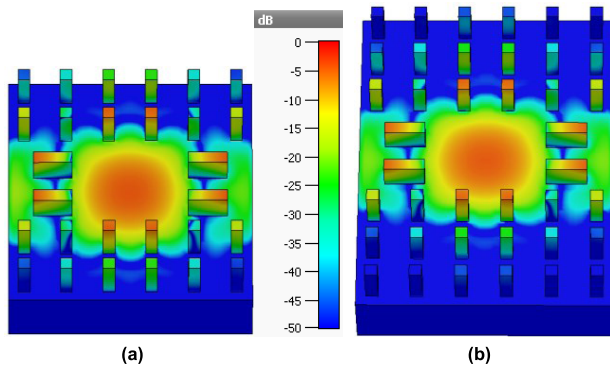


FIGURE 3. Electric field pattern of one resonator in groove gap waveguide with side pins. (a) Two rows. (b) Three rows.

The length and width of each cavity is approximately a half guide-wavelength at the desired midband frequency ( $f_o$ ),  $\lambda_g/2$ , while the height is chosen to be equal to the height of a rectangular waveguide WR28, i.e. the shorter dimension of the rectangular waveguide. The associated cavity mode is confined between the flat areas of both parallel plates and rows of side pins. Increasing the number of side pins rows will decrease the undesired leakage. However, it increases the structure complexity. In this work, to reduce the complexity of the structure with a reasonable leakage, two rows of side pins are sufficient. FIGURE 3(a) and (b) exhibit the electric field for a single gap-waveguide resonator with two and three rows of side pins, respectively. It can be observed that the leakage at the third row of sided pins in FIGURE 3(b) is lower than -40 dB which can be neglected. The resonance frequency of each resonator can be determined from its dimensions. With our design, the 35.65 GHz cavity resonator was achieved with spatial dimensions of  $5.9 \times 5.9 \times 3.1 \text{ mm}^3$ . To achieve cross-resonator coupling, a coupling pillar ( $P_{mn}$ ) is longitudinally centered in parallel with two periodic pins between any two adjacent resonators, as illustrated in FIGURE 4.

To study the effect of each spatial dimension, the normalized coupling coefficient between Resonators #1 and #2,  $m_{12}$  ( $m_{12} = M_{12} / FBW$ ), is plotted as a function of the pillar length ( $P_{12\_l}$ ) and pillar height ( $P_{12\_h}$ ), as illustrated in FIGURE 5. These plots are the design curves for the normalized coupling coefficient  $m$  between adjacent resonators. Due to symmetry,  $P_{12}$  and  $P_{34}$  are identical. The dimensions of  $P_{23}$  were evaluated in the same way (results not shown). To achieve cross-resonator coupling, a pair of inductive irises are placed between Resonators #1 and #4, as illustrated in FIGURE 4. The thickness of these irises is the same as the pins, and their height ( $iris\_h$ ) is fixed to pin height plus gap separation distance (i.e., the irises touch the internal surfaces of both plates). The normalized coupling coefficient  $m_{14}$  is plotted as a function of the iris width ( $iris\_w$ ), as shown in FIGURE 5.

Couplings between the input source and Resonator #1 and also between Resonator #4 and the output load, are realized by placing two pairs of pillars ( $H$ ), with the first and

TABLE 2. Initial and optimized BPF spatial dimensions (mm).

Parameter	Description	Initial Value	Optimized Value
$g$	gap separation	1.00	1.00
$t$	pin thickness	0.50	0.70
$h$	pin height	2.00	2.10
$p$	pin period	2.00	2.20
$P_{12\_h}$	pillar height for Res. #1_Res.#2	1.72	1.70
$P_{12\_l}$	pillar length for Res. #1_Res.#2	1.27	1.25
$P_{23\_h}$	pillar height for Res. #2_Res.#3	2.20	2.33
$P_{23\_l}$	pillar length for Res. #2_Res.#3	1.50	1.70
$iris\_h$	iris height	3.00	3.10
$iris\_w$	iris width	1.92	1.90
$H\_h$	input/output pillar height	1.64	1.67
$H\_l$	input/output pillar length	0.91	0.92

fourth resonators connected to WR-28 rectangular waveguide ports, respectively. The length of  $H$  ( $H\_l$ ) controls the resonance frequency, while its height ( $H\_h$ ) controls the external quality factor, as shown in FIGURE 6. Although the resonance frequency is slightly affected by changes of input/output pillar height, this can be compensated by optimizing the input/output pillar length. The initial structural dimensions are given in TABLE 2. A final optimization process is then applied to fine tune the spatial dimensions of the filter structure, to fully meet the target frequency response specifications.

## IV. SIMULATIONS AND MEASUREMENTS

### A. SIMULATED RESULTS

Full-wave electromagnetic simulations were undertaken using CST MICROWAVE STUDIO®. The metal was modeled as copper. The whole structure of the optimized BPF is shown in FIGURE 4. FIGURE 7 shows the simulated scattering (S)-parameters of the final optimized filter. It can be seen that the simulated performance satisfies the design specifications. The minimum insertion loss  $IL$  within the passband is 0.4 dB (with a passband average of 0.45 dB) and the passband return loss  $RL$  is better than 22 dB. Two transmission zeros are introduced at 34.89 GHz and 36.52 GHz, as a result of the cross-coupling between Resonators #1 and #4. Near-symmetrical bandstop attenuation of  $\sim 50$  dB is predicted.

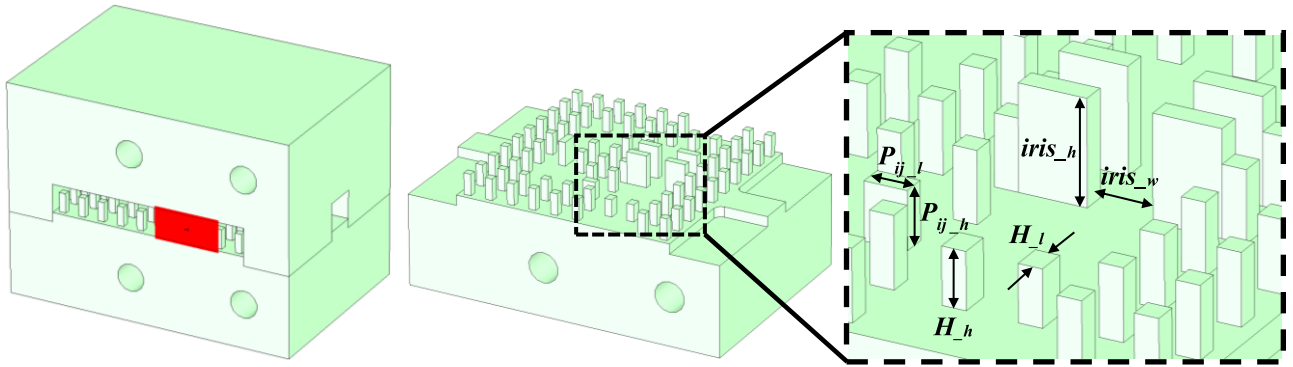


FIGURE 4. Proposed filter structure (dimensional values listed in TABLE 2).

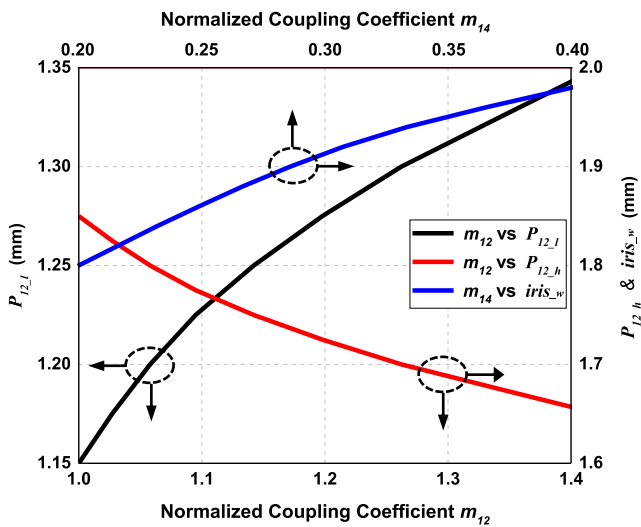


FIGURE 5. Normalized coupling coefficients  $m_{12}$  as a function of  $P_{12,l}$  and  $P_{12,h}$ , and  $m_{14}$  as a function of  $iris_w$  (with  $iris_h = h = g$ ).

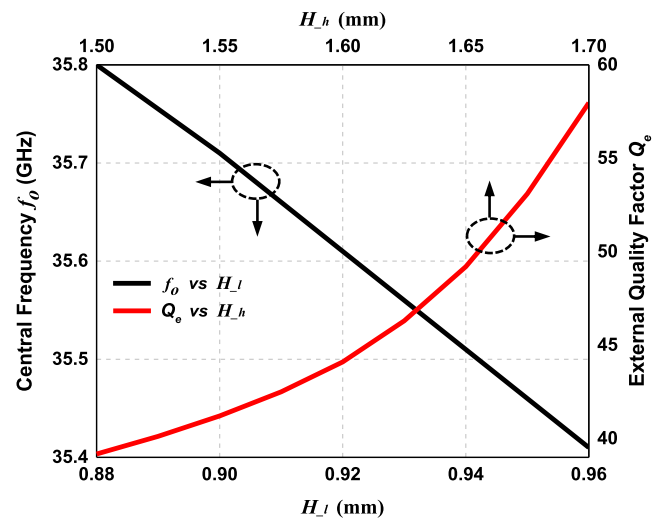


FIGURE 6. Center frequency of a doubly-loaded resonator as a function of  $H_l$  ( $H_h = 1.5$  mm) and the external quality factor as a function of  $H_h$  ( $H_l = 1.2$  mm).

**B. FABRICATION PROCESSING**

As illustrated in FIGURE 4, the filter structure is split into two parts; this simplifies the fabrication process of the pins, as well as to avoid problems with metal plating. The filter was fabricated using a 3D Systems’ Projet 2500 printer, which provides near state-of-the-art resolution ( $800 \times 900 \times 790$  DPI,  $32 \mu\text{m}$  layers). The parts are formed by jetting of photopolymers from multiple nozzles, to form each layer that are immediately selectively UV cured, to form structure and support areas as defined by the CAD file. This technology represents the highest resolution in the commercial 3-D printing of plastics that can be achieved for large structures. Once printed, the parts are baked at  $60^\circ\text{C}$ , to allow the supporting wax to melt away. To further remove any wax residue, the parts are cleaned further in a  $70^\circ\text{C}$  ultrasonic bath of EZ-Rinse for 15 minutes and a room temperature ultrasonic bath of IPA for 15 minutes. These cleaned parts were then commercially electroless-plated with  $20 \mu\text{m}$  thick copper, exceeding five skin depths of thickness at the lowest frequency of operation. The final Polyjet 3-D printed and copper-plated BPF prototype is shown in FIGURE 8(a).

**C. MEASURED RESULTS**

The prototype BPF was measured using an Anritsu 37369A vector network analyzer (VNA) with standard WR-28 waveguide flange interfaces. A Thru-Reflect-Line (TRL) calibration technique was first performed to calibrate the VNA. The measured results are shown in FIGURE 7. At the center frequency, the measured insertion and return losses are 0.5 dB and 21 dB, respectively; only 0.1 dB and 1 dB different from predictions, respectively. The measured transmission zeros are slightly further out than predicted. This is mainly due to the manufacturing tolerance. The width of the irises between Resonators #1 and #4 is a few microns shorter than in the design. Nevertheless, it should be noted that there were no iterations to the fabrication and no tuning was needed to achieve these measured results.

The measured results of the 3-D printed filter are compared with our previous design [21], as shown in FIGURE 8(b), which was fabricated from brass using a machining technology. Here, a computer numerical control (CNC) milling machine was used to create the periodic

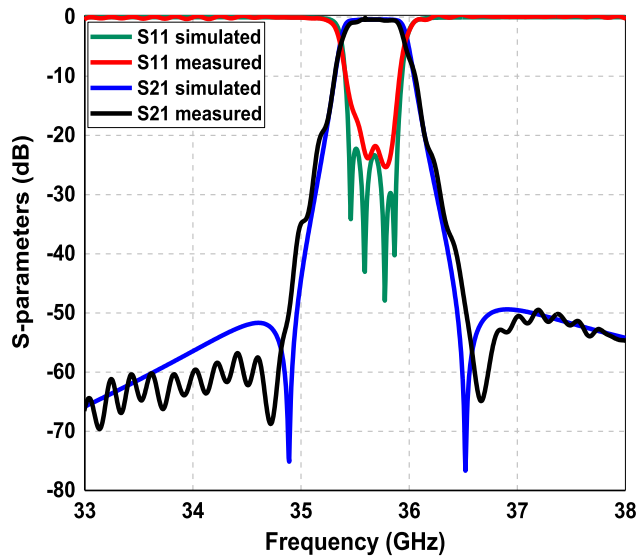


FIGURE 7. Simulated and measured results for the Polyjet 3-D printed BPF.

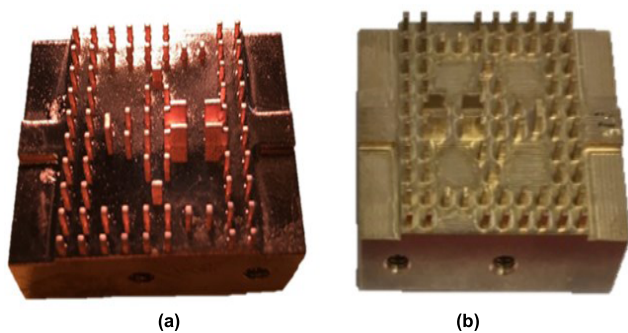


FIGURE 8. Prototype Ka-band BPFs: (a) Polyjet 3-D printed (weighing 17 g); and (b) CNC machined (weighing 112 g).

structure and four cavities on the bottom plate. The measured forward transmission and reflection coefficients,  $S_{21}$  and  $S_{11}$ , respectively, of both filters are shown in FIGURE 9, along with the simulated results. It can be seen that there are obvious differences between the measured results of the 3-D printed and machined filters. The measured insertion and return losses for the machined filter were 1.2 dB and 11 dB, respectively; significantly worse than with the new Polyjet 3-D printed counterpart. The insertion loss is more with the CNC BPF, because of the lower bulk conductivity of brass when compared to copper.

Moreover, when compared to the machined filter, very little frequency shift is observed with the Polyjet 3-D printed counterpart. These improvements are mainly due to the high fabrication accuracy offered by Polyjet 3-D printing. Though the precision of CNC machines is usually higher than Polyjet 3-D printers, it is difficult to keep the accuracy equal over a whole structure (changes over the manufacturing time period) especially with such complex bed of nails. In addition to the excellent measured performance, another important advantage of the 17 g Polyjet 3-D printed component is the

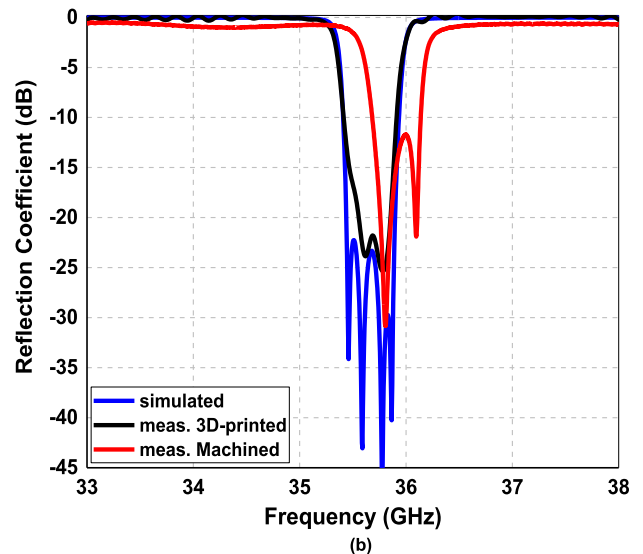
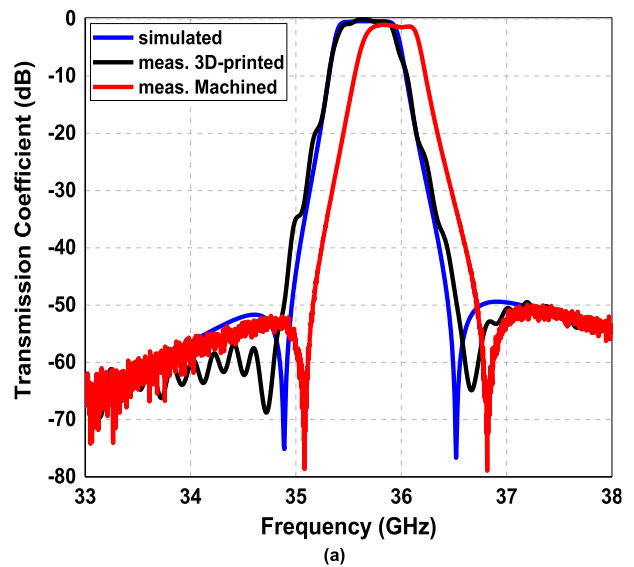


FIGURE 9. Simulated and measured performances for the Polyjet 3-D printed and machined prototype Ka-band BPFs: (a) transmission responses; (b) reflection responses.

dramatic reduction in mass, when compared to the 112 g brass CNC machined counterpart; an 85% weight reduction, while having the same geometric dimensions. Finally, TABLE 3 compares the filter with recently reported mm-wave GGW-based BPFs, fabricated using machining technology (mass was not included, due to a lack of available data). It can be seen that our Polyjet 3-D printed BPF has the lowest insertion loss and the second narrowest bandwidth.

Furthermore, good selectivity was achieved with high stopband attenuation. Clearly, the low mass and excellent measured performance of our prototype filter make it ideally suited for aerospace applications. For such applications, development time and all associated cost are also important drivers – the proposed fabrication technology has the advantages of short production development time and relatively low material costs.

**TABLE 3.** Comparison of mm-wave GGW-based BPFs fabricated using different technologies.

Frequency (GHz)	Manufacturing Technology	Filter Order	FBW (%)	IL (dB)	RL (dB)	Stopband Rejection (dB)	$Q_u$	Dimensions (mm)	Ref.
37.37	CNC Machining	7	1.5	1	17	60	2000	61.6×12.0×2.8	[19]
35	CNC Machining	3	1	1	9	35	1091	17.8×16.0×12.7	[20]
35.65	CNC Machining	4	1.4	1.2	11.7	48	614	21.0×21.0×3.1	Previous work [21]
61	CNC Machining	5	2.5	1.5	13	60	677	-	[23]
<b>35.65</b>	<b>Polyjet 3-D Printing</b>	<b>4</b>	<b>1.4</b>	<b>0.5</b>	<b>21</b>	<b>52</b>	<b>1275</b>	<b>21.0×21.0×3.1</b>	<b>This work</b>

Lastly, to investigate the fabrication tolerance effect on the filter performance, a 50  $\mu\text{m}$  increment is applied to some structure dimensions and a simulation is run for each dimension change. When this increment is applied to the pin thickness, pin height and iris length, the resonance frequency of the filter is decreased by 165 MHz, the bandwidth is broadened by 80 MHz and the locations of the transmission zeros approach to the passband in about 200 MHz from both sides, respectively.

## V. CONCLUSION

Polyjet 3-D printing has been adopted to manufacture a GGW-based BPF operating at mm-wave frequencies. The 35.65 GHz 3-D printed filter presents many advantages, when compared to other manufacturing technologies, in terms of mass, performance, development time and cost. The measured results of the Polyjet 3-D printed filter are in excellent agreement with predictions, without having any design iterations or post-fabrication tuning. A high selectivity has been realized by cross-coupling between two non-adjacent resonators. The locations of the transmission zeros in the measurement are slightly further away from those seen in simulations. This is mainly because of a small fabrication error; easily corrected by introducing a single design-print iteration. The Polyjet 3-D printed BPF has been compared with the same filter fabricated using a CNC milling machine. Our new BPF has a dramatically reduced mass, lower insertion loss and less frequency shift. Finally, when compared to recently reported mm-wave GGW-based BPFs, our Polyjet 3-D printed filter exhibits excellent insertion loss and frequency selectivity with a significant low mass.

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**BAHAA AL-JUBOORI** received the B.Sc. and M.Sc. degrees from the Department of Electronics and Communications Engineering, Al-Nahrain University, Baghdad, Iraq, in 2006 and 2010, respectively.

He was a BSS Engineer with Motorola/Zain, Babylon, Iraq, from 2010 to 2012. Then, he was with Nokia Siemens Network as a Back Office Engineer, until 2014. During that time, he was working with EarthLink Telecommunications for internet services, as a part-time job.

He is currently pursuing the Ph.D. degree with the Department of Electrical Engineering and Electronics, University of Liverpool, Liverpool, U.K. His current research interests include electromagnetic millimeter-wave filters, power dividers, couplers, and diplexers.



**JIAFENG ZHOU** received the B.Sc. degree in radio physics from Nanjing University, Nanjing, China, in 1997, and the Ph.D. degree from the University of Birmingham, Birmingham, U.K., in 2004. His doctoral research concerned high-temperature superconductor microwave filters.

Since 1997, he was with the National Meteorological Satellite Centre of China, Beijing, China, for two and a half years. From 2004 to 2006, he was with the University of Birmingham, where his research concerned phased arrays for reflector observing systems. Then, he moved to the Department of Electronic and Electrical Engineering, University of Bristol, Bristol, U.K., until 2013. His research in Bristol was on the development of highly efficient and linear amplifiers. He is currently with the Department of Electrical Engineering and Electronics, University of Liverpool, Liverpool, U.K. His past and current research interests include microwave power amplifiers, filters, electromagnetic compatibility, energy harvesting, and wireless power transfer.





**YI HUANG** (S'91–M'96–SM'06) received the B.Sc. degree in physics from Wuhan University, China, in 1984, the M.Sc. (Eng) degree in microwave engineering from Nanjing Nriet Industrial Co., Ltd., (NRIET), Nanjing, China, in 1987, and the D.Phil. degree in communications from the University of Oxford, U.K., in 1994.

He has been conducting research in the areas of wireless communications, applied electromagnetics, radar, and antennas, since 1987. His experience includes three years spent with NRIET, as a Radar Engineer, and various periods with the Universities of Birmingham, Oxford, and Essex in the U.K. as a member of the research staff. He worked as a Research Fellow with British Telecom Labs, in 1994, and then joined the Department of Electrical Engineering and Electronics, University of Liverpool, U.K., as a Faculty, in 1995, where he is currently a Full Professor in wireless engineering, the Head of the High Frequency Engineering Group, and the Deputy Head of Department.

Prof. Huang has published over 300 refereed papers in leading international journals and conference proceedings. He is the principal author of *Antennas: From Theory to Practice* (John Wiley, 2008). He has received many research grants from research councils, government agencies, charity, EU and industry, acted as a consultant to various companies, and served on a number of national and international technical committees. He has been an Editor, Associate Editor or Guest Editor of four international journals. He has been a keynote/invited speaker and organizer of many conferences and workshops (e.g. WiCom 2006, 2010, IEEE iWAT 2010, and LAPC2012). He is currently the Editor-in-Chief of *Wireless Engineering and Technology*, U.K. National Rep of European Association of Antenna and Propagation and a Fellow of IET.



**MUAAD HUSSEIN** was born in Basra, Iraq. He received the B.Sc. and M.Sc. degrees in electrical engineering from the University of Basra, Iraq, in 2005, and the Ph.D. degree from the Department of Electrical Engineering and Electronics, University of Liverpool, Liverpool, U.K., in 2018.

He was a Microwave Engineer with ASIACELL Telecom., Sulaimaniyah, Iraq, for seven years. He has been a Lecturer with the Department of Electrical Power Engineering, Southern University.

His research interests focus on frequency selective surfaces, wireless power transfer, and antenna design.



**AHMED ALIEDIN** received the B.Sc. degree in radar engineering from the Military Technical College, Egypt, in 2005, and the M.Sc. (Eng) in antenna and microwave propagation from the University of Alexandria, Egypt, in 2013. He is currently pursuing the Ph.D. degree in electrical engineering with the University of Liverpool, U.K. He was a Radar Engineer under MoD, Egypt, and an Assistant Lecturer at the Air Defense College, Egypt. He also worked as an Antenna Engineer at Benha Electronics Company, where he was involved in projects of national importance. His research interests include mobile base station antennas, satellite antennas, MIMO, and phased-MIMO radar antenna arrays design.



**WILLIAM J. OTTER** (S'12–M'15) received the M.Eng. degree in electrical and electronic engineering and the Ph.D. degree from Imperial College London, London, U.K., in 2010 and 2015, respectively.

During his M.Eng. degree, he undertook industrial placement with BAE Systems, Advanced Technology Centre, Great Baddow, U.K., and held an IET FUSE Scholarship. Throughout his Ph.D., he held the Val O'Donoghue Scholarship at the

Department of Electrical and Electronic Engineering.

He is currently a Post-Doctoral Research Associate with Imperial College London, working in the area of millimeter-wave and THz bio-sensors. His current research interests include 3-D printing, photonic crystals, low-cost terahertz devices, electromagnetic modeling, optoelectronics, and electromagnetic sensors.



**DIRK KLUGMANN** received the German Diplom (roughly equivalent to M.Sc. degree), and the Ph.D. degree from Hamburg University, Germany, in 1991 and 1998, respectively. His doctoral research was centered around the globally first millimeter wave radar for atmospheric observations, exclusively utilizing semiconductor components for the RF frontend.

From 1998 to 2004, he worked with the Institute for Tropospheric Research, Leipzig, Germany.

In 2004, he incorporated the start-up business LISTaR GmbH, Leipzig, which he managed until 2009. In 2010, he joined the U.K. Met Office, where he worked as Manager of the Upper-air Sensing Team in Observations R&D until 2014.

In 2014, he started his current position with UKRI/STFC/RAL Space as a Test and Development Engineer. In parallel, he incorporated the start-up business, S&AO Ltd., which he runs part-time. Since the start of his doctoral research, his work was always focused on instruments and methods for atmospheric observations, specifically remote sensing and on the wider sensors area.



**STEPAN LUCYSZYN** (M'91–SM'04–F'14) received the Ph.D. degree in electronic engineering from King's College London, University of London, London, U.K., in 1992, and the D.Sc. (higher doctorate) degree in millimeter-wave and terahertz electronics from Imperial College London, London, in 2010. From 1997 to 2012, he taught MMIC Measurement Techniques on IEE/IET short courses, hosted by the U.K.'s National Physical Laboratory.

He is currently a Professor of millimeter-wave systems and the Director of the Centre for Terahertz Science and Engineering, Imperial College London. He has co-authored over 200 papers and 12 book chapters in applied physics and electronic engineering.

Dr. Lucyszyn serves as a Founding Member of the Steering Group for the U.K.'s EPSRC Terahertz Network. More recently, he became a member of the IEEE Technical Committee for Terahertz Technology and Applications (MTT-4). He was made a Fellow of the Institution of Electrical Engineers, U.K., and the Institute of Physics, U.K., in 2005. In 2008, he became a Fellow of the Electromagnetics Academy, USA. He was appointed as an IEEE Distinguished Microwave Lecturer, from 2010 to 2013. He is currently a European Microwave Lecturer for the European Microwave Association. He co-founded the Imperial College London spin-out company Drayson Wireless Ltd., in 2014.

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